

MUN5211T1 Series

Preferred Devices

Bias Resistor Transistor

NPN Silicon Surface Mount Transistor with Monolithic Bias Resistor Network

This new series of digital transistors is designed to replace a single device and its external resistor bias network. The BRT (Bias Resistor Transistor) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space. The device is housed in the SC-70/SOT-323 package which is designed for low power surface mount applications.

Features

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- The SC-70/SOT-323 package can be soldered using wave or reflow. The modified gull-winged leads absorb thermal stress during soldering eliminating the possibility of damage to the die.
- Available in 8 mm embossed tape and reel. Use the Device Number to order the 7 inch/3000 unit reel.
- Pb-Free Packages are Available

MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	50	Vdc
Collector-Emitter Voltage	V_{CEO}	50	Vdc
Collector Current	I_C	100	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	202 (Note 1) 310 (Note 2) 1.6 (Note 1) 2.5 (Note 2)	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	618 (Note 1) 403 (Note 2)	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction-to-Lead	$R_{\theta JL}$	280 (Note 1) 332 (Note 2)	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature Range	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

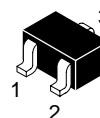
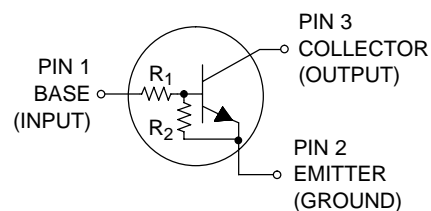
1. FR-4 @ Minimum Pad.
2. FR-4 @ 1.0 x 1.0 inch Pad.



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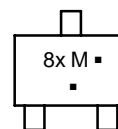
<http://onsemi.com>

NPN SILICON BIAS RESISTOR TRANSISTORS



SC-70/SOT-323
CASE 419
STYLE 3

MARKING DIAGRAM



8x = Device Code
M = Date Code*
▪ = Pb-Free Package

(Note: Microdot may be in either location)
*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

DEVICE MARKING INFORMATION

See specific marking information in the device marking table on page 2 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

MUN5211T1 Series

DEVICE MARKING AND RESISTOR VALUES

Device	Package	Marking	R1 (K)	R2 (K)	Shipping†
MUN5211T1	SC-70/SOT-323	8A	10	10	3000 / Tape & Reel
MUN5211T1G	SC-70/SOT-323 (Pb-Free)	8A	10	10	3000 / Tape & Reel
MUN5212T1	SC-70/SOT-323	8B	22	22	3000 / Tape & Reel
MUN5212T1G	SC-70/SOT-323 (Pb-Free)	8B	22	22	3000 / Tape & Reel
MUN5213T1	SC-70/SOT-323	8C	47	47	3000 / Tape & Reel
MUN5213T1G	SC-70/SOT-323 (Pb-Free)	8C	47	47	3000 / Tape & Reel
MUN5214T1	SC-70/SOT-323	8D	10	47	3000 / Tape & Reel
MUN5214T1G	SC-70/SOT-323 (Pb-Free)	8D	10	47	3000 / Tape & Reel
MUN5215T1 (Note 3)	SC-70/SOT-323	8E	10	∞	3000 / Tape & Reel
MUN5215T1G (Note 3)	SC-70/SOT-323 (Pb-Free)	8E	10	∞	3000 / Tape & Reel
MUN5216T1 (Note 3)	SC-70/SOT-323	8F	4.7	∞	3000 / Tape & Reel
MUN5216T1G (Note 3)	SC-70/SOT-323 (Pb-Free)	8F	4.7	∞	3000 / Tape & Reel
MUN5230T1 (Note 3)	SC-70/SOT-323	8G	1.0	1.0	3000 / Tape & Reel
MUN5230T1G (Note 3)	SC-70/SOT-323 (Pb-Free)	8G	1.0	1.0	3000 / Tape & Reel
MUN5231T1 (Note 3)	SC-70/SOT-323	8H	2.2	2.2	3000 / Tape & Reel
MUN5231T1G (Note 3)	SC-70/SOT-323 (Pb-Free)	8H	2.2	2.2	3000 / Tape & Reel
MUN5232T1 (Note 3)	SC-70/SOT-323	8J	4.7	4.7	3000 / Tape & Reel
MUN5232T1G (Note 3)	SC-70/SOT-323 (Pb-Free)	8J	4.7	4.7	3000 / Tape & Reel
MUN5233T1 (Note 3)	SC-70/SOT-323	8K	4.7	47	3000 / Tape & Reel
MUN5233T1G (Note 3)	SC-70/SOT-323 (Pb-Free)	8K	4.7	47	3000 / Tape & Reel
MUN5234T1 (Note 3)	SC-70/SOT-323	8L	22	47	3000 / Tape & Reel
MUN5234T1G (Note 3)	SC-70/SOT-323 (Pb-Free)	8L	22	47	3000 / Tape & Reel
MUN5235T1 (Note 3)	SC-70/SOT-323	8M	2.2	47	3000 / Tape & Reel
MUN5235T1G (Note 3)	SC-70/SOT-323 (Pb-Free)	8M	2.2	47	3000 / Tape & Reel
MUN5236T1 (Note 3)	SC-70/SOT-323	8N	100	100	3000 / Tape & Reel
MUN5236T1G (Note 3)	SC-70/SOT-323 (Pb-Free)	8N	100	100	3000 / Tape & Reel
MUN5237T1 (Note 3)	SC-70/SOT-323	8P	47	22	3000 / Tape & Reel
MUN5237T1G (Note 3)	SC-70/SOT-323 (Pb-Free)	8P	47	22	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

3. New devices. Updated curves to follow in subsequent data sheets.

MUN5211T1 Series

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Collector–Base Cutoff Current (V _{CB} = 50 V, I _E = 0)	I _{CBO}	–	–	100	nAdc
Collector–Emitter Cutoff Current (V _{CE} = 50 V, I _B = 0)	I _{CEO}	–	–	500	nAdc
Emitter–Base Cutoff Current (V _{EB} = 6.0 V, I _C = 0)	I _{EBO}	–	–	0.5	mAdc
MUN5211T1		–	–	0.2	
MUN5212T1		–	–	0.1	
MUN5213T1		–	–	0.2	
MUN5214T1		–	–	0.9	
MUN5215T1		–	–	1.9	
MUN5216T1		–	–	4.3	
MUN5230T1		–	–	2.3	
MUN5231T1		–	–	1.5	
MUN5232T1		–	–	0.18	
MUN5233T1		–	–	0.13	
MUN5234T1		–	–	0.2	
MUN5235T1		–	–	0.05	
MUN5236T1		–	–	0.13	
MUN5237T1		–	–		
Collector–Base Breakdown Voltage (I _C = 10 μA, I _E = 0)	V _{(BR)CBO}	50	–	–	Vdc
Collector–Emitter Breakdown Voltage (Note 4) (I _C = 2.0 mA, I _B = 0)	V _{(BR)CEO}	50	–	–	Vdc
ON CHARACTERISTICS (Note 4)					
DC Current Gain (V _{CE} = 10 V, I _C = 5.0 mA)	h _{FE}	35	60	–	
MUN5211T1		60	100	–	
MUN5212T1		80	140	–	
MUN5213T1		80	140	–	
MUN5214T1		160	350	–	
MUN5215T1		160	350	–	
MUN5216T1		3.0	5.0	–	
MUN5230T1		8.0	15	–	
MUN5231T1		15	30	–	
MUN5232T1		80	200	–	
MUN5233T1		80	150	–	
MUN5234T1		80	140	–	
MUN5235T1		80	150	–	
MUN5236T1		80	140	–	
MUN5237T1					
Collector–Emitter Saturation Voltage (I _C = 10 mA, I _B = 0.3 mA) (I _C = 10 mA, I _B = 5 mA) MUN5230T1/MUN5231T1 (I _C = 10 mA, I _B = 1 mA) MUN5215T1/MUN5216T1/ MUN5232T1/MUN5233T1/MUN5234T1	V _{CE(sat)}	–	–	0.25	Vdc
Output Voltage (on) (V _{CC} = 5.0 V, V _B = 2.5 V, R _L = 1.0 kΩ)	V _{OL}	–	–	0.2	Vdc
MUN5211T1		–	–	0.2	
MUN5212T1		–	–	0.2	
MUN5214T1		–	–	0.2	
MUN5215T1		–	–	0.2	
MUN5216T1		–	–	0.2	
MUN5230T1		–	–	0.2	
MUN5231T1		–	–	0.2	
MUN5232T1		–	–	0.2	
MUN5233T1		–	–	0.2	
MUN5234T1		–	–	0.2	
MUN5235T1		–	–	0.2	
(V _{CC} = 5.0 V, V _B = 3.5 V, R _L = 1.0 kΩ)		–	–	0.2	
(V _{CC} = 5.0 V, V _B = 5.5 V, R _L = 1.0 kΩ)		–	–	0.2	
(V _{CC} = 5.0 V, V _B = 4.0 V, R _L = 1.0 kΩ)		–	–	0.2	

4. Pulse Test: Pulse Width < 300 μs, Duty Cycle < 2.0%

MUN5211T1 Series

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Typ	Max	Unit
ON CHARACTERISTICS (Note 5) (Continued)					
Output Voltage (off) (V _{CC} = 5.0 V, V _B = 0.5 V, R _L = 1.0 kΩ) (V _{CC} = 5.0 V, V _B = 0.050 V, R _L = 1.0 kΩ) (V _{CC} = 5.0 V, V _B = 0.25 V, R _L = 1.0 kΩ)	V _{OH}	4.9	–	–	Vdc
Input Resistor	R ₁				kΩ
MUN5211T1		7.0	10	13	
MUN5212T1		15.4	22	28.6	
MUN5213T1		32.9	47	61.1	
MUN5214T1		7.0	10	13	
MUN5215T1		7.0	10	13	
MUN5216T1		3.3	4.7	6.1	
MUN5230T1		0.7	1.0	1.3	
MUN5231T1		1.5	2.2	2.9	
MUN5232T1		3.3	4.7	6.1	
MUN5233T1		3.3	4.7	6.1	
MUN5234T1		15.4	22	28.6	
MUN5235T1		1.54	2.2	2.86	
MUN5236T1		70	100	130	
MUN5237T1		32.9	47	61.1	
Resistor Ratio	R ₁ /R ₂				
MUN5211T1/MUN5212T1/MUN5213T1/ MUN5236T1		0.8	1.0	1.2	
MUN5214T1		0.17	0.21	0.25	
MUN5215T1/MUN5216T1		–	–	–	
MUN5230T1/MUN5231T1/MUN5232T1		0.8	1.0	1.2	
MUN5233T1		0.055	0.1	0.185	
MUN5234T1		0.38	0.47	0.56	
MUN5235T1		0.038	0.047	0.056	
MUN5237T1		1.7	2.1	2.6	

5. Pulse Test: Pulse Width < 300 μs, Duty Cycle < 2.0%

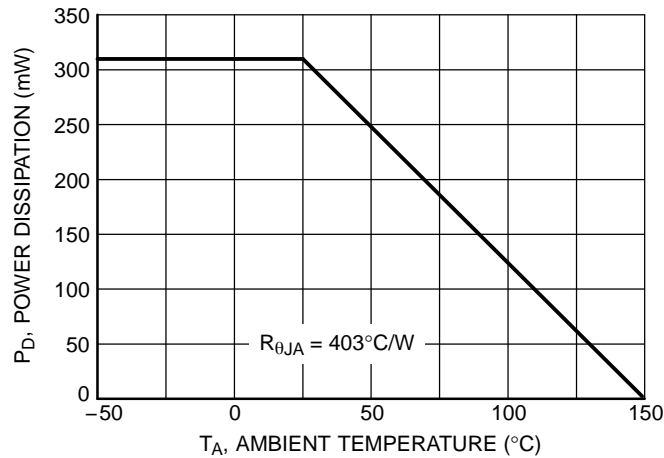


Figure 1. Derating Curve

MUN5211T1 Series

TYPICAL ELECTRICAL CHARACTERISTICS – MUN5211T1

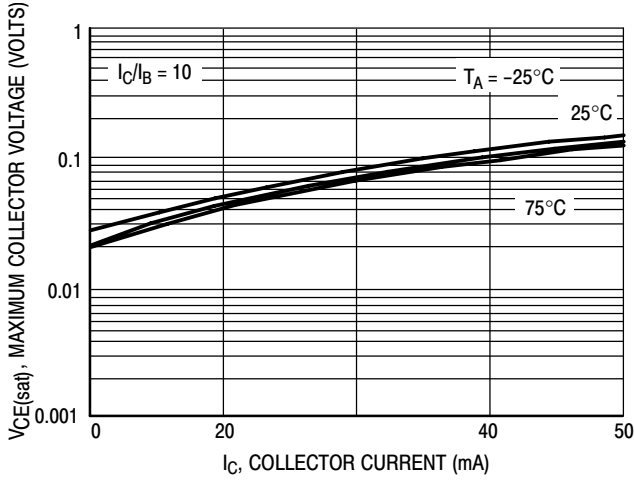


Figure 2. $V_{CE(sat)}$ versus I_C

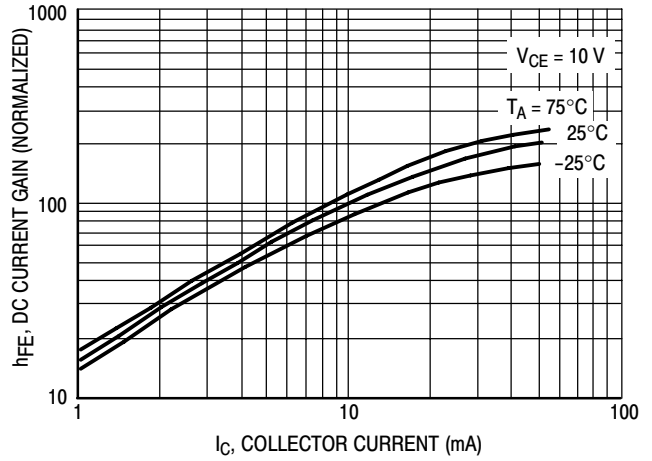


Figure 3. DC Current Gain

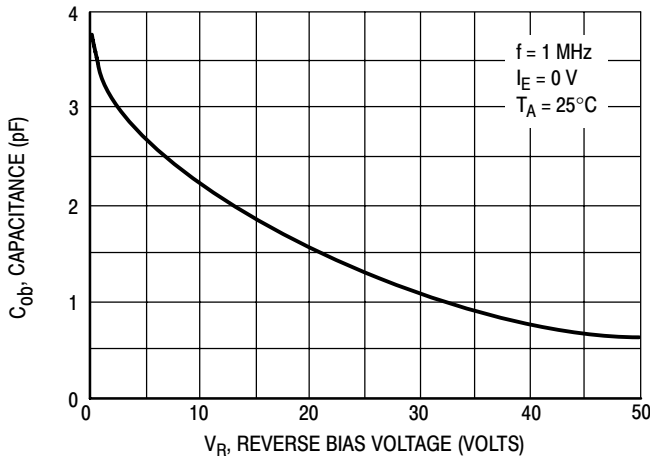


Figure 4. Output Capacitance

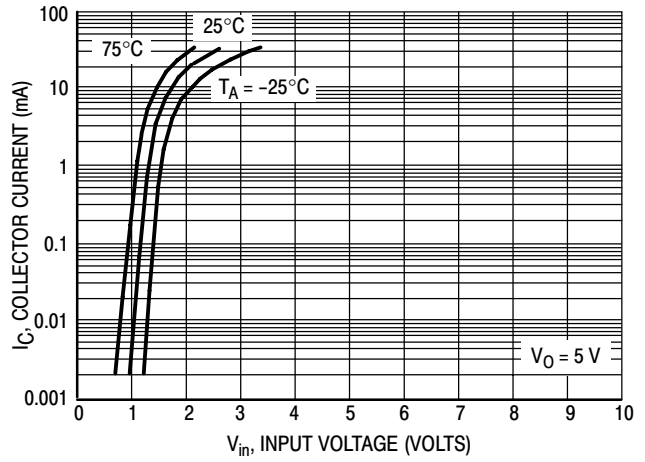


Figure 5. Output Current versus Input Voltage

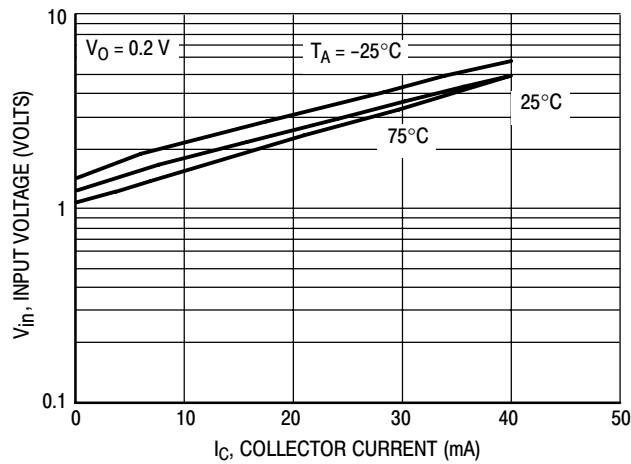


Figure 6. Input Voltage versus Output Current

MUN5211T1 Series

TYPICAL ELECTRICAL CHARACTERISTICS – MUN5212T1

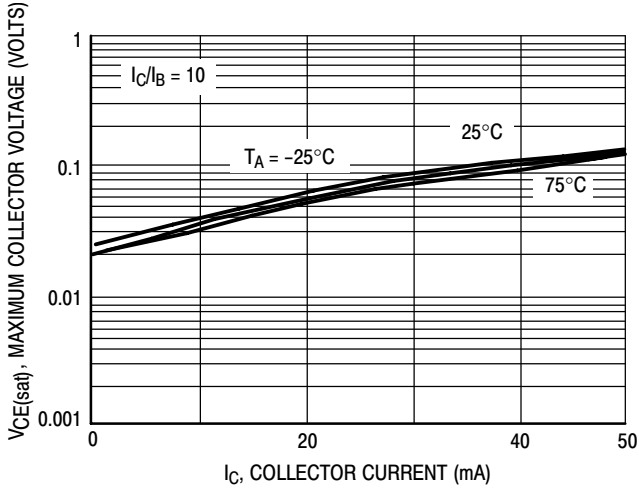


Figure 7. $V_{CE(sat)}$ versus I_C

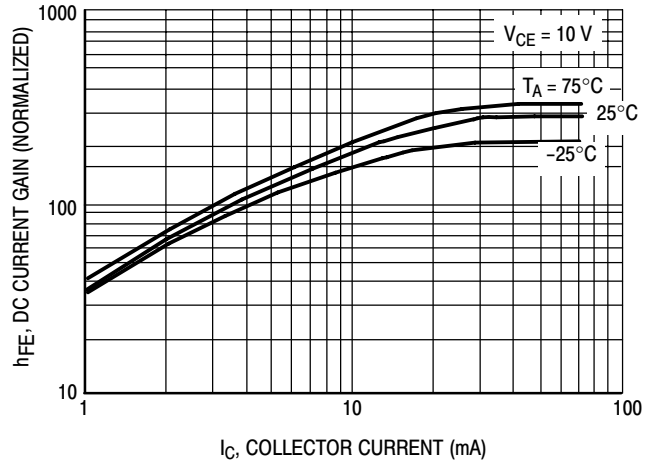


Figure 8. DC Current Gain

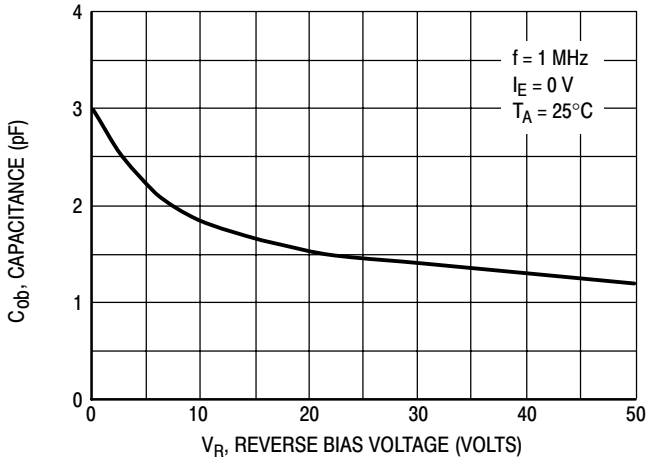


Figure 9. Output Capacitance

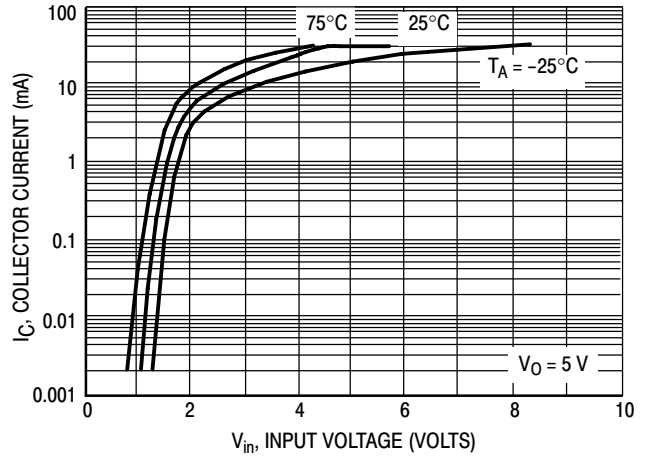


Figure 10. Output Current versus Input Voltage

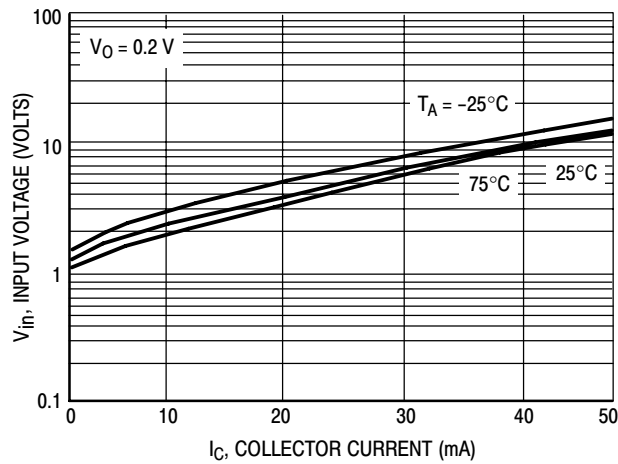


Figure 11. Input Voltage versus Output Current

MUN5211T1 Series

TYPICAL ELECTRICAL CHARACTERISTICS – MUN5213T1

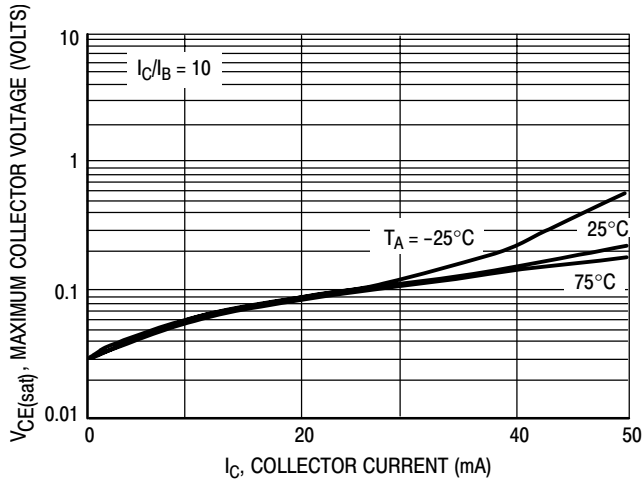


Figure 12. $V_{CE(sat)}$ versus I_C

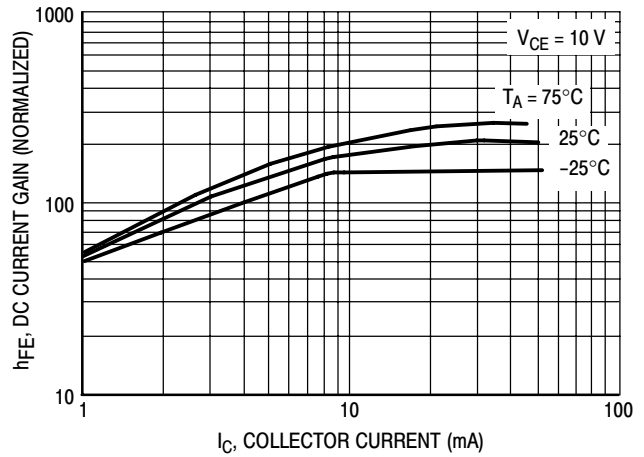


Figure 13. DC Current Gain

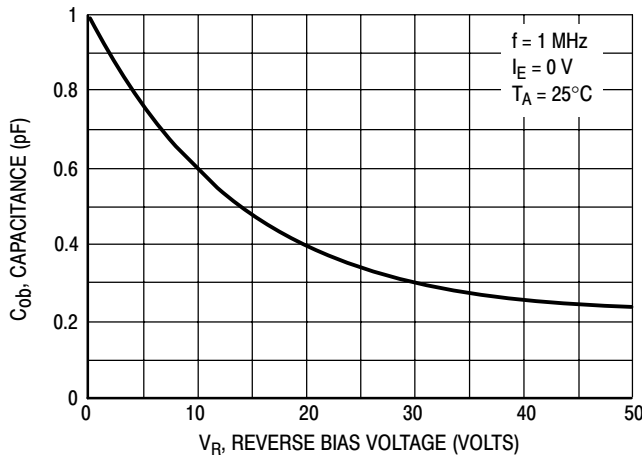


Figure 14. Output Capacitance

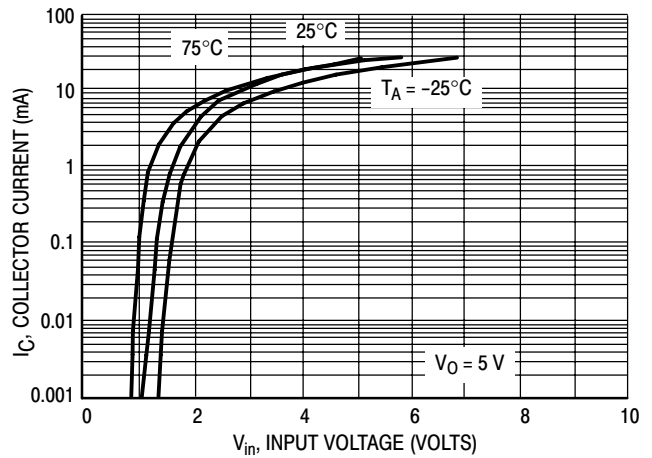


Figure 15. Output Current versus Input Voltage

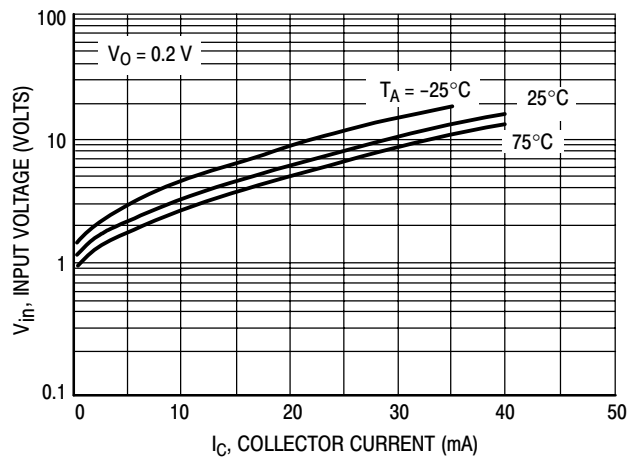


Figure 16. Input Voltage versus Output Current

MUN5211T1 Series

TYPICAL ELECTRICAL CHARACTERISTICS – MUN5214T1

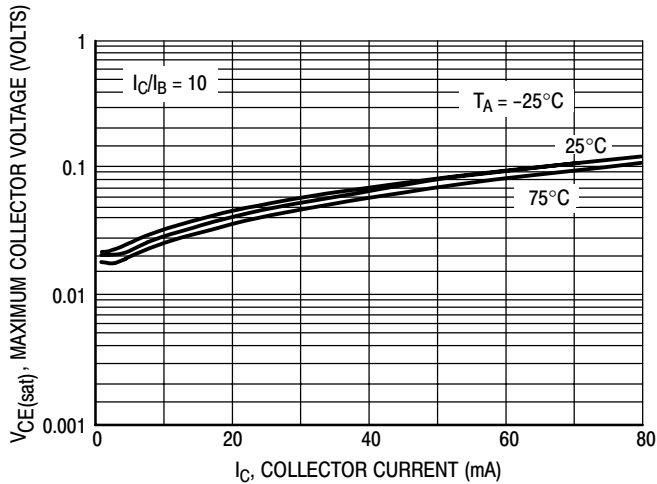


Figure 17. $V_{CE(sat)}$ versus I_C

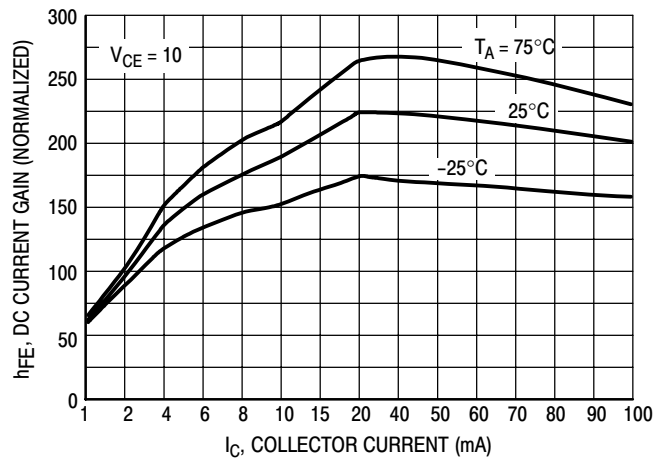


Figure 18. DC Current Gain

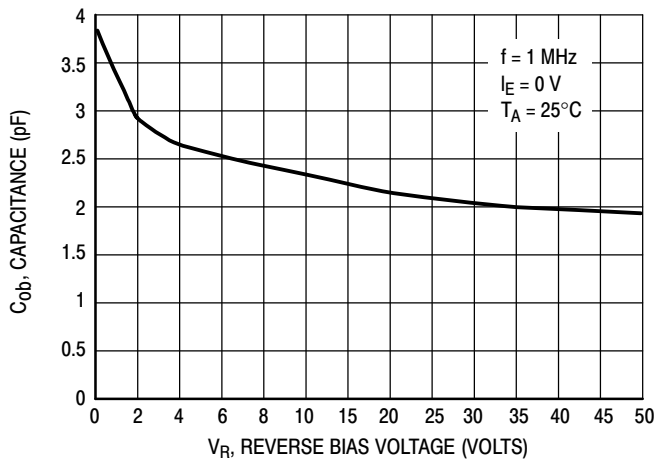


Figure 19. Output Capacitance

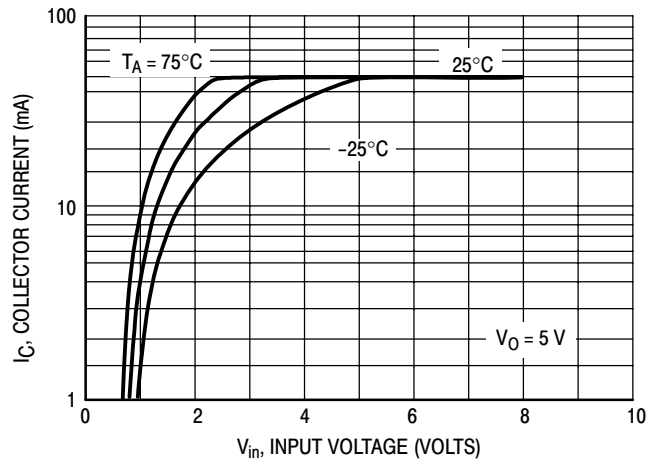


Figure 20. Output Current versus Input Voltage

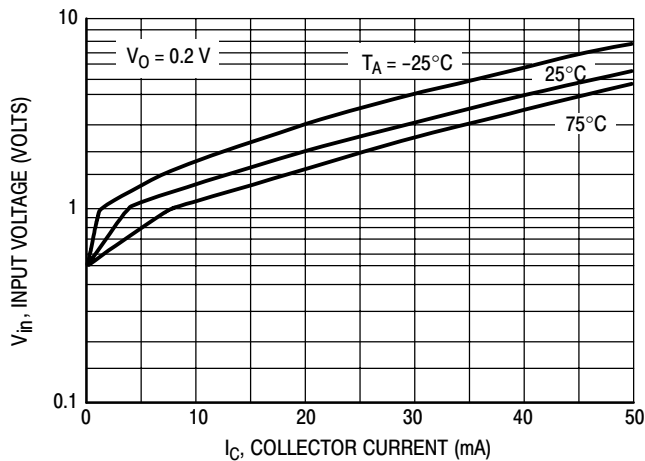


Figure 21. Input Voltage versus Output Current

MUN5211T1 Series

TYPICAL APPLICATIONS FOR NPN BRTs

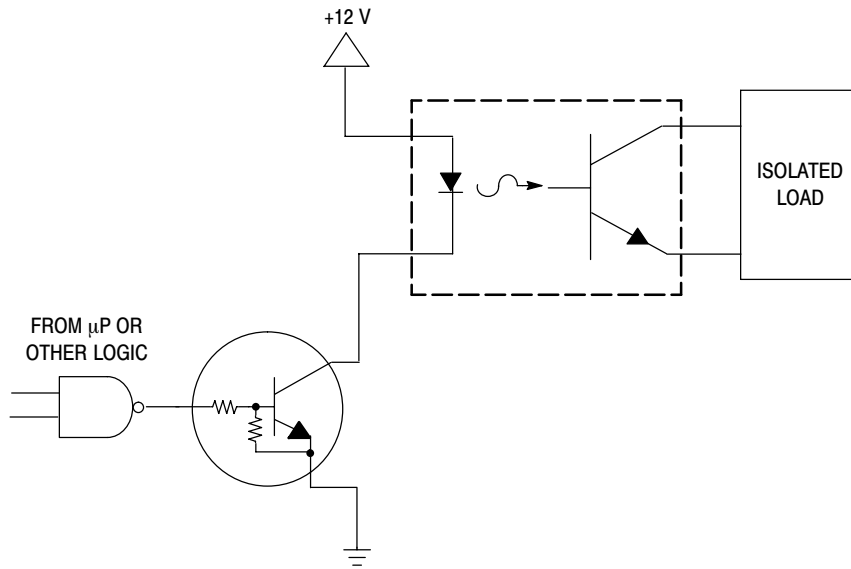


Figure 22. Level Shifter: Connects 12 or 24 Volt Circuits to Logic

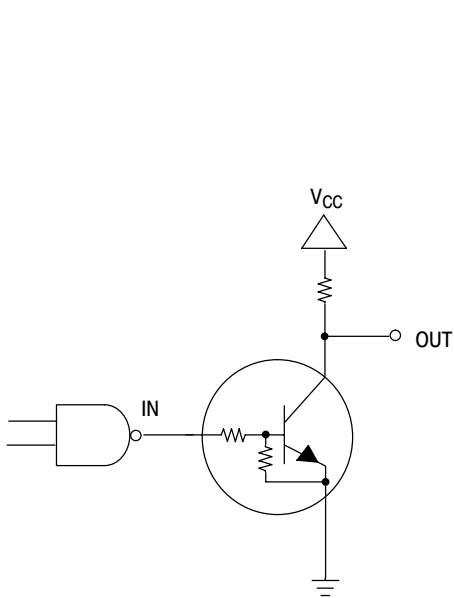


Figure 23. Open Collector Inverter: Inverts the Input Signal

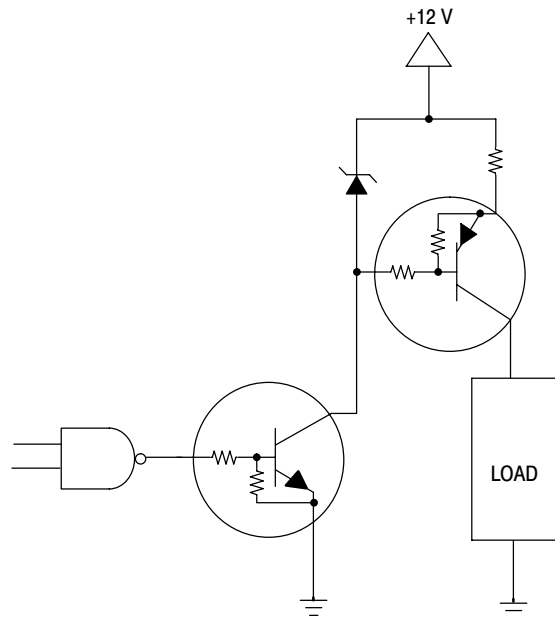
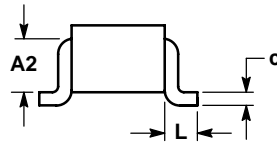
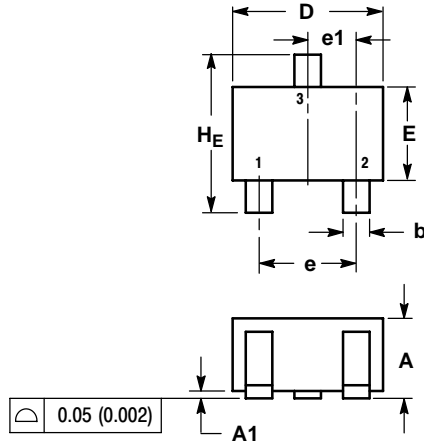


Figure 24. Inexpensive, Unregulated Current Source

MUN5211T1 Series

PACKAGE DIMENSIONS

SC-70/SOT-323
CASE 419-04
ISSUE M

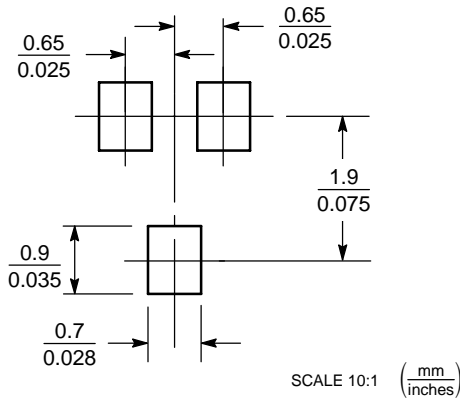


- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.80	0.90	1.00	0.032	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2	0.7 REF			0.028 REF		
b	0.30	0.35	0.40	0.012	0.014	0.016
c	0.10	0.18	0.25	0.004	0.007	0.010
D	1.80	2.10	2.20	0.071	0.083	0.087
E	1.15	1.24	1.35	0.045	0.049	0.053
e	1.20	1.30	1.40	0.047	0.051	0.055
e1	0.65 BSC			0.026 BSC		
L	0.425 REF			0.017 REF		
HE	2.00	2.10	2.40	0.079	0.083	0.095

- STYLE 3:
PIN 1. BASE
2. EMITTER
3. COLLECTOR

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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